

# SANYO Semiconductors DATA SHEET

# CPH5614—General-Purpose Switching Device Applications

### **Features**

- · Low ON-resistance.
- · Ultrahigh-speed switching.
- 4V drive.
- · Composite type with 2 MOSFETs contained in a single package, facilitaing high-density mounting.

# **Specifications**

#### Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	VDSS		100	V
Gate-to-Source Voltage	VGSS		±20	V
Drain Current (DC)	ID		1	Α
Drain Current (Pulse)	IDP	PW≤10μs, duty cycle≤1%	4	Α
Allowable Power Dissipation	PD	Mounted on a ceramic board (600mm <sup>2</sup> X0.8mm) 1unit	0.9	W
Channel Temperature	Tch		150	°C
Storage Temperature	Tstg		-55 to +150	°C

#### Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Linit
			min	typ	max	Unit
Drain-to-Source Breakdown Voltage	V(BR)DSS	I <sub>D</sub> =1mA, V <sub>G</sub> S=0	100			V
Zero-Gate Voltage Drain Current	IDSS	V <sub>DS</sub> =100V, V <sub>GS</sub> =0			1	μΑ
Gate-to-Source Leakage Current	IGSS	VGS=±16V, VDS=0			±10	μΑ
Cutoff Voltage	VGS(off)	V <sub>DS</sub> =10V, I <sub>D</sub> =1mA	1.2		2.6	V
Forward Transfer Admittance	yfs	V <sub>DS</sub> =10V, I <sub>D</sub> =500mA	0.98	1.4		S
Static Drain-to-Source On-State Resistance	RDS(on)1	ID=500mA, VGS=10V		480	630	mΩ
	R <sub>DS</sub> (on)2	ID=500mA, VGS=4V		580	810	mΩ
Input Capacitance	Ciss	VDS=20V, f=1MHz		240		pF
Output Capacitance	Coss	V <sub>DS</sub> =20V, f=1MHz		20		pF
Reverse Transfer Capacitance	Crss	V <sub>DS</sub> =20V, f=1MHz		12		pF
Turn-ON Delay Time	t <sub>d</sub> (on)	See specified Test Circuit.		8		ns
Rise Time	tr	See specified Test Circuit.		3		ns
Turn-OFF Delay Time	t <sub>d</sub> (off)	See specified Test Circuit.		30		ns
Fall Time	tf	See specified Test Circuit.		11		ns

Marking: FW Continued on next page.

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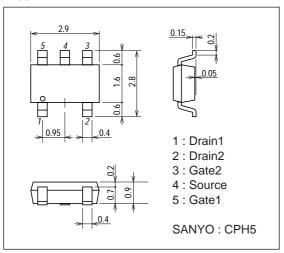
# **CPH5614**

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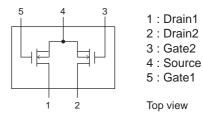
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Offic
Total Gate Charge	Qg	V <sub>DS</sub> =50V, V <sub>GS</sub> =10V, I <sub>D</sub> =1A		6.5		nC
Gate-to-Source Charge	Qgs	V <sub>DS</sub> =50V, V <sub>GS</sub> =10V, I <sub>D</sub> =1A		1.1		nC
Gate-to-Drain "Miller" Charge	Qgd	V <sub>DS</sub> =50V, V <sub>GS</sub> =10V, I <sub>D</sub> =1A		1.1		nC
Diode Forward Voltage	VSD	IS=1A, VGS=0		0.82	1.2	V

# **Package Dimensions**

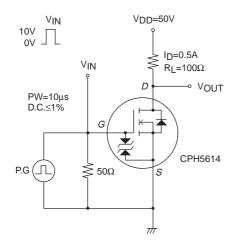
unit : mm 2168

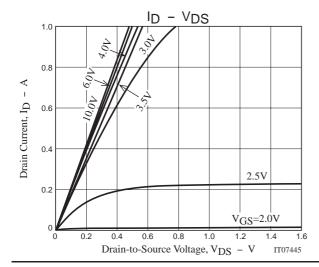


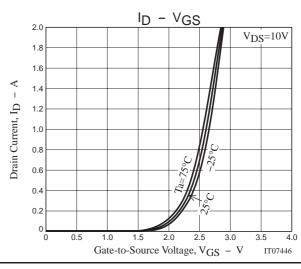
# **Electrical Connection**

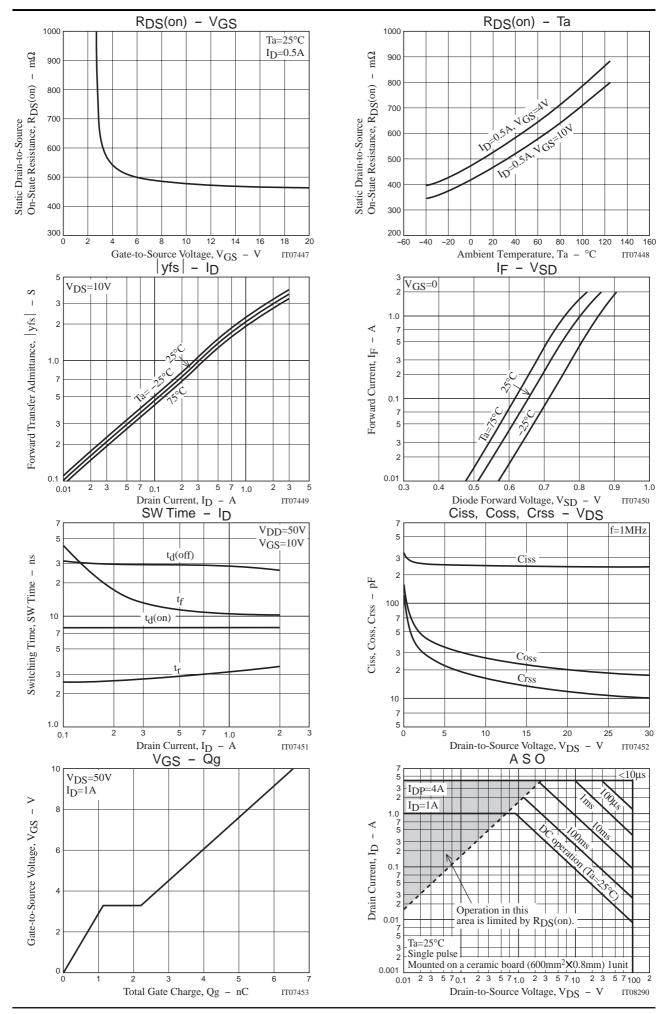


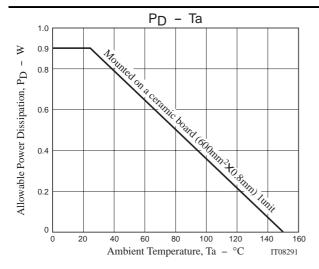
# **Switching Time Test Circuit**











Note on usage: Since the CPH5614 is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

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